

# LM567/LM567C Tone Decoder

#### FEATURES

- 20 to 1 Frequency Range with an External Resistor
- Logic Compatible Output with 100 mA Current Sinking Capability
- Bandwidth Adjustable from 0 to 14%
- High Rejection of Out of Band Signals and Noise
- Immunity to False Signals
- Highly Stable Center Frequency
- Center Frequency Adjustable from 0.01 Hz to 500 kHz

### **APPLICATIONS**

- Touch Tone Decoding
- Precision Oscillator
- Frequency Monitoring and Control
- Wide Band FSK Demodulation
- Ultrasonic Controls
- Carrier Current Remote Controls
- Communications Paging Decoders

#### DESCRIPTION

The LM567 and LM567C are general purpose tone decoders designed to provide a saturated transistor switch to ground when an input signal is present within the passband. The circuit consists of an I and Q detector driven by a voltage controlled oscillator which determines the center frequency of the decoder. External components are used to independently set center frequency, bandwidth and output delay.

#### OUTPUT 1 8 OUTPUT FILTER I PHASE DETECTOR 2 LOOP 7 GND FILTER vco 3 6 Q PHASE DETECTOR TIMING INPUT CAPACITOR 4 5 TIMING RESISTOR

Figure 2. PDIP and SOIC Packages Top View

### **CONNECTION DIAGRAM**



#### ABSOLUTE MAXIMUM RATINGS<sup>(1)(2)(3)</sup>

| Supply Voltage Pin               | 9V                    |
|----------------------------------|-----------------------|
| Power Dissipation <sup>(4)</sup> | 1100 mW               |
| V <sub>8</sub>                   | 15V                   |
| V <sub>3</sub>                   | -10V                  |
| V <sub>3</sub>                   | V <sub>4</sub> + 0.5V |
| Storage Temperature Range        | −65°C to +150°C       |
| Operating Temperature Range      |                       |
| LM567H                           | −55°C to +125°C       |
| LM567CH, LM567CM, LM567CN        | 0°C to +70°C          |
| Soldering Information            |                       |
| PDIP Package                     |                       |
| Soldering (10 sec.)              | 260°C                 |
| SOIC Package                     |                       |
| Vapor Phase (60 sec.)            | 215°C                 |
| Infrared (15 sec.)               | 220°C                 |

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. Electrical Characteristics state DC and AC electrical specifications under particular test conditions which ensure specific performance limits. This assumes that the device is within the Operating Ratings. Specifications are not ensured for parameters where no limit is given, however, the typical value is a good indication of device performance.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.
- (3) Refer to RETS567X drawing for specifications of military LM567H version.

(4) The maximum junction temperature of the LM567 and LM567C is 150°C. For operating at elevated temperatures, devices in the TO-5 package must be derated based on a thermal resistance of 150°C/W, junction to ambient or 45°C/W, junction to case. For the DIP the device must be derated based on a thermal resistance of 110°C/W, junction to ambient. For the SOIC package, the device must be derated based on a thermal resistance of 160°C/W, junction to ambient.

#### ELECTRICAL CHARACTERISTICS

AC Test Circuit,  $T_A = 25^{\circ}C$ ,  $V^+ = 5V$ 

| Parameters   | Conditions  | LM567 |      |     | LM567C |      |     | Unite      |
|--|---|-------|------|-----|--------|------|-----|------------|
|  |   | Min   | Тур  | Max | Min    | Тур  | Max | Units      |
| Power Supply Voltage Range                                 |   | 4.75  | 5.0  | 9.0 | 4.75   | 5.0  | 9.0 | V          |
| Power Supply Current Quiescent                             | $R_L = 20k$   |       | 6    | 8   |        | 7    | 10  | mA         |
| Power Supply Current Activated                             | $R_L = 20k$   |       | 11   | 13  |        | 12   | 15  | mA         |
| Input Resistance   |   | 18    | 20   |     | 15     | 20   |     | kΩ         |
| Smallest Detectable Input Voltage                          | $I_{L} = 100 \text{ mA}, f_{i} = f_{o}$             |       | 20   | 25  |        | 20   | 25  | mVrms      |
| Largest No Output Input Voltage                            | $I_{\rm C} = 100 \text{ mA}, f_{\rm i} = f_{\rm o}$ | 10    | 15   |     | 10     | 15   |     | mVrms      |
| Largest Simultaneous Outband Signal to Inband Signal Ratio |   |       | 6    |     |        | 6    |     | dB         |
| Minimum Input Signal to Wideband Noise<br>Ratio            | B <sub>n</sub> = 140 kHz                            |       | -6   |     |        | -6   |     | dB         |
| Largest Detection Bandwidth                                |   | 12    | 14   | 16  | 10     | 14   | 18  | % of $f_o$ |
| Largest Detection Bandwidth Skew                           |   |       | 1    | 2   |        | 2    | 3   | % of $f_o$ |
| Largest Detection Bandwidth Variation with Temperature     |   |       | ±0.1 |     |        | ±0.1 |     | %/°C       |
| Largest Detection Bandwidth Variation with Supply Voltage  | 4.75–6.75V  |       | ±1   | ±2  |        | ±1   | ±5  | %V         |
| Highest Center Frequency                                   |   | 100   | 500  |     | 100    | 500  |     | kHz        |



### **ELECTRICAL CHARACTERISTICS (continued)**

AC Test Circuit,  $T_A = 25^{\circ}C$ ,  $V^+ = 5V$ 

| Parameters                                 | Conditions  | LM567 |                     |            | LM567C |                     |            | Unite            |
|--|---|-------|---------------------|------------|--------|---------------------|------------|------------------|
|  |   | Min   | Тур                 | Max        | Min    | Тур                 | Max        | Units            |
| Center Frequency Stability (4.75–5.75V)    | 0 < T <sub>A</sub> < 70<br>−55 < T <sub>A</sub> < +125                                    |       | 35 ± 60<br>35 ± 140 |            |        | 35 ± 60<br>35 ± 140 |            | ppm/°C<br>ppm/°C |
| Center Frequency Shift with Supply Voltage | 4.75V–6.75V<br>4.75V–9V   |       | 0.5                 | 1.0<br>2.0 |        | 0.4                 | 2.0<br>2.0 | %/V<br>%/V       |
| Fastest ON-OFF Cycling Rate                |   |       | f <sub>o</sub> /20  |            |        | f <sub>o</sub> /20  |            |                  |
| Output Leakage Current                     | V <sub>8</sub> = 15V  |       | 0.01                | 25         |        | 0.01                | 25         | μA               |
| Output Saturation Voltage                  | $e_i = 25 \text{ mV}, I_8 = 30 \text{ mA}$<br>$e_i = 25 \text{ mV}, I_8 = 100 \text{ mA}$ |       | 0.2<br>0.6          | 0.4<br>1.0 |        | 0.2<br>0.6          | 0.4<br>1.0 | V                |
| Output Fall Time                           |   |       | 30                  |            |        | 30                  |            | ns               |
| Output Rise Time                           |   |       | 150                 |            |        | 150                 |            | ns               |





SCHEMATIC DIAGRAM





#### **TYPICAL PERFORMANCE CHARACTERISTICS**



 $T_A = 25^{\circ}C$ 

 $V_{CC} = 5V$ 

1k

10k

CENTER FREQUENCY (Hz)

Figure 8.

100k

0

100

1M





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#### **TYPICAL APPLICATIONS**



Component values (typ) R1 6.8 to 15k R2 4.7k R3 20k C1 0.10 mfd C2 1.0 mfd 6V C3 2.2 mfd 6V C4 250 mfd 6V









Connect Pin 3 to 2.8V to Invert Output





Figure 15. Oscillator with Double Frequency Output



Figure 16. Precision Oscillator Drive 100 mA Loads



### AC TEST CIRCUIT



 $\label{eq:fi} \begin{array}{l} f_i = 100 \ \text{kHz} + 5\text{V} \\ \text{*Note: Adjust for } f_o = 100 \ \text{kHz}. \end{array}$ 

#### **APPLICATIONS INFORMATION**

The center frequency of the tone decoder is equal to the free running frequency of the VCO. This is given by

$$f_o \cong \frac{1}{1.1 R_1 C_1}$$

The bandwidth of the filter may be found from the approximation

BW = 1070 
$$\sqrt{\frac{V_i}{f_o C_2}}$$
 in % of  $f_o$ 

where

- $V_i$  = Input voltage (volts rms),  $V_i \le 200 \text{mV}$
- C<sub>2</sub> = Capacitance at Pin 2(µF)

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